


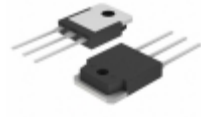
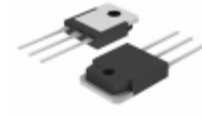


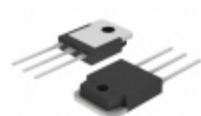


	<h2 style="color: red;">FQA33N10</h2>
	<p>Hersteller-Teilenummer: FQA33N10</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 36A TO-3P</p> <p>Datenblätter:  FQA33N10.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7151 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA33N10
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 36A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7151 pcs Stock
detaillierte Beschreibung	N-Channel 100V 36A (Tc) 163W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	163W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	36A (Tc)
Rds On (Max) @ Id, Vgs	52 mOhm @ 18A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	51nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQA33N10 ist neu im Original, Suche FQA33N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA33N10 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA33N10: Info@Y-IC.com

Sie können auch interessiert sein:

 FQA30N40 AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 30A TO-3P	 FQA33N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 36A TO-3P	 FQA32N20C AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 32A TO-3P	 FQA34N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 34A TO-3P
 FQA34N20 Fairchild/ON Semiconductor MOSFET N-CH 200V 34A TO-3P	 FQA33N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 36A TO-3P	 FQA33N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 36A TO-3P	 FQA32N20C Fairchild/ON Semiconductor MOSFET N-CH 200V 32A TO-3P

heiße Teile

Mehr

 FQA20N40	 FQA20N40	 FQA20N50	 FQA20N60	 FQA20N80
 FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F	 FQA24N60
 FQA24N60	 FQA27N25	 FQA27N25	 FQA28N15	 FQA28N15
 FQA28N15_F109	 FQA28N15_F109	 FQA28N50	 FQA28N50	 FQA28N50F
 FQA28N50F	 FQA30N40	 FQA30N40	 FQA32N20C	 FQA32N20C
 FQA33N10	 FQA33N10L	 FQA33N10L	 FQA34N20	 FQA34N20
 FQA34N20L	 FQA34N20L	 FQA34N25	 FQA34N25	 FQA35N40
 FQA35N40	 FQA36P15	 FQA36P15	 FQA36P15_F109	 FQA36P15_F109
 FQA38N30	 FQA38N30	 FQA40N25	 FQA40N25	 FQA40N30
 FQA40N50	 FQA40N50L	 FQA44N10	 FQA44N10	 FQA44N30

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